## NSN 5961-01-259-3798

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Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-259-3798 **Inclosure Material:** Metal **Overall Length:** 1.570 inches **Overall Height:** 0.447 inches **Overall Width:** 1.020 inches **Mounting Facility Quantity: Internal Configuration:** Field effect Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-3 **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 120.0 drain to source voltage **Current Rating Per Characteristic:** 7.00 amperes drain current **Power Rating Per Characteristic:** 100.0 watts collector power dissipation **Terminal Type And Quantity:** 2 pin and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:** No